TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SZ125F,TC7SZ125FU

### Bus Buffer 3-State Output

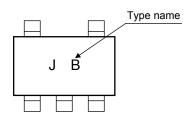
### **Features**

- High output drive: ±24 mA (min) @VCC = 3 V
- Super high speed operation:

 $t_{pd}$  2.6 ns (typ.) @V<sub>CC</sub> = 5 V, 50 pF

- Operation voltage range:  $V_{CC \text{ (opr)}} = 1.8 \sim 5.5 \text{ V}$
- Power down protection is provided on all inputs and outputs.
- $\bullet$  Matches the performance of TC74LCX series when operated at 3.3 V  $V_{\rm CC}.$

### Marking



# TC7SZ125F SSOP5-P-0.95 TC7SZ125FU SSOP5-P-0.65A

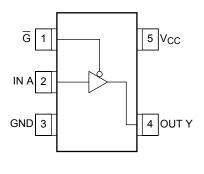
Weight

SSOP5-P-0.95 SSOP5-P-0.65A : 0.016 g (typ.) : 0.006 g (typ.)

# Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	-0.5~6	V	
DC input voltage	V <sub>IN</sub>	-0.5~6	٧	
DC output voltage	V <sub>OUT</sub>	-0.5~6	V	
Input diode current	l <sub>IK</sub>	±20	mA	
Output diode current	I <sub>OK</sub>	±20	mA	
DC output current	lout	±50	mA	
DC V <sub>CC</sub> /ground current	I <sub>CC</sub>	±50	mA	
Power dissipation	P <sub>D</sub>	200	mW	
Storage temperature	T <sub>stg</sub>	-65~150	°C	
Lead temperature (10s)	TL	260	°C	

## Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



# **Logic Diagram**



# **Truth Table**

Inp	out	Output			
Α	Ġ	Y			
Х	Н	Z			
L	L	L			
Н	L	Н			

X: Don't Care

Z: High Impedance

# **Operating Ranges**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	1.8~5.5	V
Supply voltage	VCC	1.5~5.5 (Note 1)	V
Input voltage	V <sub>IN</sub>	0~5.5	V
Output voltage	V <sub>OUT</sub>	0~5.5 (Note 2)	V
		0~V <sub>CC</sub> (Note 3)	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
		$0~20~(V_{CC} = 1.8~V, 2.5~V \pm 0.2~V)$	
Input rise and fall time	dt/dv	$0 \sim 10 \ (V_{CC} = 3.3 \ V \pm 0.3 \ V)$	ns/V
		$0~5~(V_{CC} = 5.5~V \pm 0.5~V)$	

Note 1: Data retention only

Note 2:  $V_{CC} = 0 V$ 

Note 3: H and Low state



# **Electrical Characteristics**

### **DC Characteristics**

Characteristics Sym		Symbol	Test Condition			Ta = 25°C			Ta = -40~85°C		- Unit
Characteris	Sucs	Symbol	1 EST CONDITION		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
High level		V <sub>IH</sub>			1.8	0.88 × V <sub>CC</sub>	ı	_	0.88 × V <sub>CC</sub>	_	
Input voltage	riigirievei	VIH	_		2.3~5.5	0.75 × V <sub>CC</sub>		_	0.75 × V <sub>CC</sub>	_	V
input voitage	Low level	VIL	. –		1.8		I	0.12 × V <sub>CC</sub>		0.12 × V <sub>CC</sub>	
	Low level	VIL			2.3~5.5	_		0.25 × V <sub>CC</sub>	_	0.25 × V <sub>CC</sub>	
					1.8	1.7	1.8	_	1.7	_	
				I <sub>OH</sub> = -100 μA	2.3	2.2	2.3	_	2.2	_	
				10Η = 100 μΑ	3.0	2.9	3.0	_	2.9	_	
	High level	Vou	V.s. – V		4.5	4.4	4.5	—	4.4	_	
	i ligii level	VOH	V <sub>IN</sub> = V <sub>IH</sub>	$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15	_	1.9	_	
				$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.8	_	2.4	_	
				$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68	_	2.3	_	
Output valtage			$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.2	_	3.8	_	V	
Output voltage	Output voltage			I <sub>OL</sub> = 100 μA	1.8	_	0	0.1	_	0.1	- -
					2.3	_	0	0.1	_	0.1	
					3.0	_	0	0.1	_	0.1	
	Low level	\/a.	V V		4.5	_	0	0.1	_	0.1	
	LOW level	VOL	$V_{IN} = V_{IL}$	$I_{OL} = 8 \text{ mA}$	2.3	_	0.1	0.3	_	0.3	
			I <sub>OL</sub> = 16 mA	3.0	_	0.15	0.4	_	0.4		
			I <sub>OL</sub> = 24 mA	3.0	_	0.22	0.55	_	0.55		
	I <sub>OL</sub> =	I <sub>OL</sub> = 32 mA	4.5	_	0.22	0.55	_	0.55			
Input leakage curre	ent	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0~5.5	_	_	±1	_	±10	μА
3-state output off-s	tate current	loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \sim 5.5 \text{ V}$		1.8~5.5		_	±1	_	±10	μΑ
Power off leakage	current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0.0	_	_	1	_	10	μА
Quiescent supply c	urrent	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_		2	_	20	μА

# AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

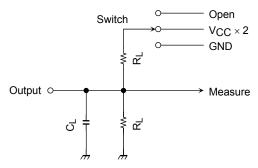
Characteristics	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Symbol	rest Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
	t <sub>pLH</sub>	$C_L$ = 15 pF, $R_L$ = 1 M $\Omega$	1.8	2.0	5.3	11.0	2.0	11.5	- ns
			$2.5\pm0.2$	8.0	3.4	7.5	8.0	8.0	
Propagation delay time			$3.3 \pm 0.3$	0.5	2.5	5.2	0.5	5.5	
Tropagation delay time	t <sub>pHL</sub>		$5.0\pm0.5$	0.5	2.1	4.5	0.5	4.8	
		C <sub>L</sub> = 50 pF,	$3.3 \pm 0.3$	1.5	3.2	5.7	1.5	6.0	
		$R_L = 500 \Omega$	$5.0\pm0.5$	8.0	2.6	5.0	0.8	5.3	
	t <sub>pZL</sub> t <sub>pZH</sub>	$\begin{array}{c} C_L = 50 \text{ pF}, \\ R_L = 500 \ \Omega \end{array}$	1.8	2.0	7.0	12.5	2.0	13.0	ns ns
Output enable time			$2.5 \pm 0.2$	1.5	4.6	8.5	1.5	9.0	
			$3.3 \pm 0.3$	1.5	3.5	6.2	1.5	6.5	
			$5.0\pm0.5$	8.0	2.8	5.5	0.8	5.8	
Output disable time	t <sub>pLZ</sub>	$C_L = 50 \text{ pF},$ $R_L = 500 \ \Omega$	1.8	2.0	5.4	11.0	2.0	12.0	ns .
			$2.5\pm0.2$	1.5	3.5	8.0	1.5	8.5	
			$3.3 \pm 0.3$	1.0	2.8	5.7	1.0	6.0	
			$5.0\pm0.5$	0.5	2.1	4.7	0.5	5.0	
Input capacitance	C <sub>IN</sub>	_	0~5.5	_	4	_	_	_	pF
Power dissination canacitance	Power dissipation capacitance C <sub>PD</sub>	(Note 4)	3.3		17		_		- pF
1 ower dissipation capacitance			5.5		24			_	

Note 4: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

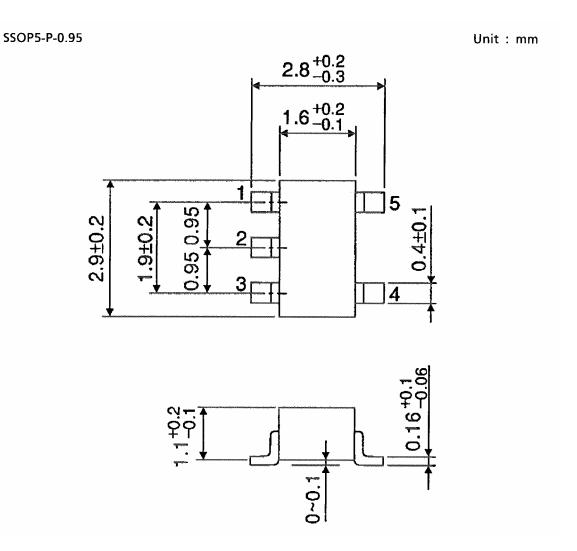
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

### **AC Characteristics Measurement Circuit**



Characteristics	Switch
t <sub>pLH</sub> , t <sub>pHL</sub>	Open
$t_{pLZ}, t_{pZL}$	$V_{CC} \times 2$
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND

# **Package Dimensions**



Weight: 0.016 g (typ.)

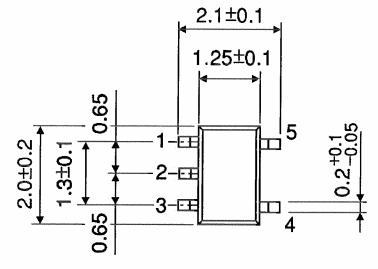
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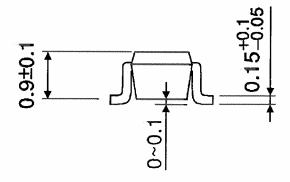
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# **Package Dimensions**

SSOP5-P-0.65A Unit: mm





Weight: 0.006 g (typ.)

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20070701-EN GENERAL

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